

MA2D755

Silicon epitaxial planar type

For switching power supply

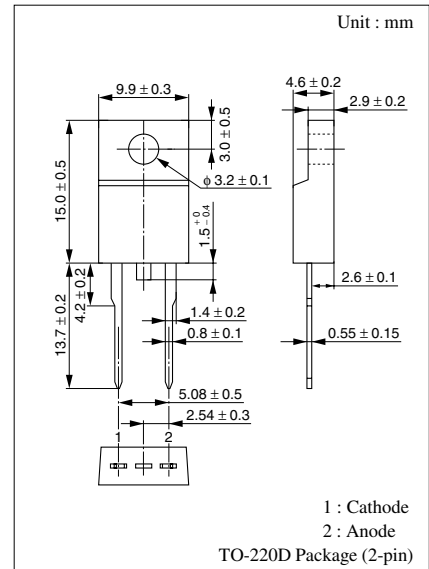
■ Features

- TO-220D Package
- Allowing to rectify under ($I_{F(AV)} = 5 \text{ A}$) condition
- $V_R = 60 \text{ V}$ guaranteed
- Single type

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}	60	V
Average forward current	$I_{F(AV)}$	5	A
Non-repetitive peak forward surge current*	I_{FSM}	90	A
Junction temperature	T_j	-40 to +125	$^\circ\text{C}$
Storage temperature	T_{stg}	-40 to +125	$^\circ\text{C}$

Note) * : The peak-to-peak value in one cycle of 50 Hz sine-wave (non-repetitive)



■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse current (DC)	I_R	$V_R = 60 \text{ V}$			3	mA
Forward voltage (DC)	V_F	$I_F = 5 \text{ A}$			0.58	V
Thermal resistance	$R_{th(j-c)}$	Direct current (between junction and case)			3	$^\circ\text{C/W}$

Note) Rated input/output frequency: 150 kHz

